Preferred Device

## 5 Watt Surmetic<sup>™</sup> 40 Zener Voltage Regulators

This is a complete series of 5 Watt Zener diodes with tight limits and better operating characteristics that reflect the superior capabilities of silicon-oxide passivated junctions. All this in an axial lead, transfer-molded plastic package that offers protection in all common environmental conditions.

#### Features

- Zener Voltage Range 3.3 V to 200 V
- ESD Rating of Class 3 (>16 kV) per Human Body Model
- Surge Rating of up to 180 W @ 8.3 ms
- Maximum Limits Guaranteed on up to Six Electrical Parameters
- Pb-Free Packages are Available

#### **Mechanical Characteristics**

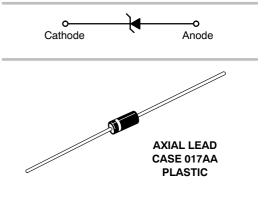
**CASE:** Void free, transfer-molded, thermosetting plastic **FINISH:** All external surfaces are corrosion resistant and leads are readily solderable

MAXIMUM LEAD TEMPERATURE FOR SOLDERING PURPOSES: 230°C, 1/16 in. from the case for 10 seconds POLARITY: Cathode indicated by polarity band MOUNTING POSITION: Any

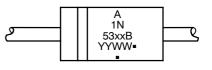


## **ON Semiconductor®**

http://onsemi.com







#### A = Assembly Location 1N53xxB = Device Number (Refer to Tables on Pages 3 & 4 YY = Year WW = Work Week = Pb-Free Package (Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
1N53xxB, G	Axial Lead (Pb-Free)	1000 Units/Box
1N53xxBRL, G	Axial Lead (Pb-Free)	4000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

**Preferred** devices are recommended choices for future use and best overall value.

#### MAXIMUM RATINGS

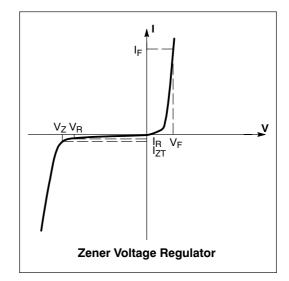
Rating	Symbol	Value	Unit
Max. Steady State Power Dissipation @ $T_L = 75^{\circ}C$ , Lead Length = 3/8 in	P <sub>D</sub>	5	W
Derate above 75°C		40	mW/°C
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +200	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted, V<sub>F</sub> = 1.2 V Max @ I<sub>F</sub> = 1.0 A for all types)

Symbol	Parameter
VZ	Reverse Zener Voltage @ IZT
I <sub>ZT</sub>	Reverse Current
Z <sub>ZT</sub>	Maximum Zener Impedance @ I <sub>ZT</sub>
I <sub>ZK</sub>	Reverse Current
Z <sub>ZK</sub>	Maximum Zener Impedance @ I <sub>ZK</sub>
I <sub>R</sub>	Reverse Leakage Current @ V <sub>R</sub>
V <sub>R</sub>	Breakdown Voltage
١ <sub>F</sub>	Forward Current
V <sub>F</sub>	Forward Voltage @ I <sub>F</sub>
I <sub>R</sub>	Maximum Surge Current @ $T_A = 25^{\circ}C$
$\Delta V_Z$	Reverse Zener Voltage Change
I <sub>ZM</sub>	Maximum DC Zener Current



		Zen	er Volta	age (Not	te 2)	Zener Imp	edance (Not	ie 2)	Leaka Curre		I <sub>B</sub>	ΔVz	I <sub>ZM</sub>
Device <sup>†</sup> Device		V <sub>Z</sub> (Volts)		@ I <sub>ZT</sub>	Z <sub>ZT</sub> @ I <sub>ZT</sub> Z <sub>ZK</sub> @ I <sub>ZK</sub>		I <sub>ZK</sub>	I <sub>R</sub> @ V <sub>R</sub>		(Note 3)	(Note 4)	(Note 5)	
(Note 1)	Marking	Min	Nom	Max	mA	Ω	Ω	mA	μ <b>Α Μах</b>	Volts	Α	Volts	mA
1N5333B, G	1N5333B	3.14	3.3	3.47	380	3	400	1	300	1	20	0.85	1440
1N5334B, G	1N5334B	3.42	3.6	3.78	350	2.5	500	1	150	1	18.7	0.8	1320
1N5335B, G	1N5335B	3.71	3.9	4.10	320	2	500	1	50	1	17.6	0.54	1220
1N5336B, G	1N5336B	4.09	4.3	4.52	290	2	500	1	10	1	16.4	0.49	1100
1N5337B, G	1N5337B	4.47	4.7	4.94	260	2	450	1	5	1	15.3	0.44	1010
1N5338B, G	1N5338B	4.85	5.1	5.36	240	1.5	400	1	1	1	14.4	0.39	930
1N5339B, G	1N5339B	5.32	5.6	5.88	220	1	400	1	1	2	13.4	0.25	865
1N5340B, G	1N5340B	5.70	6.0	6.30	200	1	300	1	1	3	12.7	0.19	790
1N5341B, G	1N5341B	5.89	6.2	6.51	200	1	200	1	1	3	12.4	0.1	765
1N5342B, G	1N5342B	6.46	6.8	7.14	175	1	200	1	10	5.2	11.5	0.15	700
1N5343B, G	1N5343B	7.13	7.5	7.88	175	1.5	200	1	10	5.7	10.7	0.15	630
1N5344B, G	1N5344B	7.79	8.2	8.61	150	1.5	200	1	10	6.2	10	0.2	580
1N5345B, G	1N5345B	8.27	8.7	9.14	150	2	200	1	10	6.6	9.5	0.2	545
1N5346B, G	1N5346B	8.65	9.1	9.56	150	2	150	1	7.5	6.9	9.2	0.22	520
1N5347B, G	1N5347B	9.50	10	10.5	125	2	125	1	5	7.6	8.6	0.22	475
1N5348B, G	1N5348B	10.45	11	11.55	125	2.5	125	1	5	8.4	8.0	0.25	430
1N5349B, G	1N5349B	11.4	12	12.6	100	2.5	125	1	2	9.1	7.5	0.25	395
1N5350B, G	1N5350B	12.35	13	13.65	100	2.5	100	1	1	9.9	7.0	0.25	365
1N5351B, G	1N5351B	13.3	14	14.7	100	2.5	75	1	1	10.6	6.7	0.25	340
1N5352B, G	1N5352B	14.25	15	15.75	75	2.5	75	1	1	11.5	6.3	0.25	315
1N5353B, G	1N5353B	15.2	16	16.8	75	2.5	75	1	1	12.2	6.0	0.3	295
1N5354B, G	1N5354B	16.15	17	17.85	70	2.5	75	1	0.5	12.9	5.8	0.35	280
1N5355B, G	1N5355B	17.1	18	18.9	65	2.5	75	1	0.5	13.7	5.5	0.4	264
1N5356B, G	1N5356B	18.05	19	19.95	65	3	75	1	0.5	14.4	5.3	0.4	250
1N5357B, G	1N5357B	19	20	21	65	3	75	1	0.5	15.2	5.1	0.4	237
1N5358B, G	1N5358B	20.9	22	23.1	50	3.5	75	1	0.5	16.7	4.7	0.45	216
1N5359B, G	1N5359B	22.8	24	25.2	50	3.5	100	1	0.5	18.2	4.4	0.55	198
1N5360B, G	1N5360B	23.75	25	26.25	50	4	110	1	0.5	19	4.3	0.55	190
1N5361B, G	1N5361B	25.65	27	28.35	50	5	120	1	0.5	20.6	4.1	0.6	176
1N5362B, G	1N5362B	26.6	28	29.4	50	6	130	1	0.5	21.2	3.9	0.6	170

#### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted, $V_F = 1.2 \text{ V Max} @ I_F = 1.0 \text{ A for all types}$ )

Devices listed in bold, italic are ON Semiconductor Preferred devices. Preferred devices are recommended choices for future use and best overall value. 1. TOLERANCE AND TYPE NUMBER DESIGNATION

The JEDEC type numbers shown indicate a tolerance of  $\pm 5\%$ .

2. ZENER VOLTAGE (Vz) and IMPEDANCE (IzT and IzK)

Test conditions for zener voltage and impedance are as follows: Iz is applied 40 ±10 ms prior to reading. Mounting contacts are located 3/8" to 1/2'' from the inside edge of mounting clips to the body of the diode (T<sub>A</sub> = 25°C +8°C, -2°C).

3. SURGE CURRENT (I<sub>R</sub>)

Surge current is specified as the maximum allowable peak, non-recurrent square-wave current with a pulse width, PW, of 8.3 ms. The data given in Figure 5 may be used to find the maximum surge current for a square wave of any pulse width between 1 ms and 1000 ms by plotting the applicable points on logarithmic paper. Examples of this, using the 3.3 V and 200 V zener are shown in Figure 6. Mounting contact located as specified in Note 2 ( $T_A = 25^{\circ}C + 8^{\circ}C, -2^{\circ}C$ ).

#### 4. VOLTAGE REGULATION ( $\Delta V_Z$ )

The conditions for voltage regulation are as follows: Vz measurements are made at 10% and then at 50% of the Iz max value listed in the electrical characteristics table. The test current time duration for each V<sub>7</sub> measurement is 40 ±10 ms. Mounting contact located as specified in Note 2 (T<sub>A</sub> = 25°C +8°C, -2°C). 5. MAXIMUM REGULATOR CURRENT (I<sub>ZM</sub>)

The maximum current shown is based on the maximum voltage of a 5% type unit, therefore, it applies only to the B-suffix device. The actual I<sub>ZM</sub> for any device may not exceed the value of 5 watts divided by the actual V<sub>Z</sub> of the device. T<sub>L</sub> = 75°C at 3/8" maximum from the device body.

†The "G" suffix indicates Pb-Free package available.

		Zener Voltage (Note 7)			Zener Impedance (Note 7)			Leakage Current		I <sub>B</sub>	ΔV7	I <sub>ZM</sub>	
Device <sup>†</sup>	Device	v	z (Volts	5)	@ I <sub>ZT</sub>	<b>Z</b> ZT @ IZT	Z <sub>ZK</sub> @ I <sub>ZK</sub>	I <sub>ZK</sub>	I <sub>R</sub> @	V <sub>R</sub>	(Note 8)	(Note 9)	(Note 10)
(Note 6)	Marking	Min	Nom	Мах	mA	Ω	Ω	mA	μ <b>Α Μax</b>	Volts	А	Volts	mA
1N5363B, G	1N5363B	28.5	30	31.5	40	8	140	1	0.5	22.8	3.7	0.6	158
1N5364B, G	1N5364B	31.35	33	34.65	40	10	150	1	0.5	25.1	3.5	0.6	144
1N5365B, G	1N5365B	34.2	36	37.8	30	11	160	1	0.5	27.4	3.5	0.65	132
1N5366B, G	1N5366B	37.05	39	40.95	30	14	170	1	0.5	29.7	3.1	0.65	122
1N5367B, G	1N5367B	40.85	43	45.15	30	20	190	1	0.5	32.7	2.8	0.7	110
1N5368B, G	1N5368B	44.65	47	49.35	25	25	210	1	0.5	35.8	2.7	0.8	100
1N5369B, G	1N5369B	48.45	51	53.55	25	27	230	1	0.5	38.8	2.5	0.9	93
1N5370B, G	1N5370B	53.2	56	58.8	20	35	280	1	0.5	42.6	2.3	1.0	86
1N5371B, G	1N5371B	57	60	63	20	40	350	1	0.5	45.5	2.2	1.2	79
1N5372B, G	1N5372B	58.9	62	65.1	20	42	400	1	0.5	47.1	2.1	1.35	76
1N5373B, G	1N5373B	64.6	68	71.4	20	44	500	1	0.5	51.7	2.0	1.52	70
1N5374B, G	1N5374B	71.25	75	78.75	20	45	620	1	0.5	56	1.9	1.6	63
1N5375B, G	1N5375B	77.9	82	86.1	15	65	720	1	0.5	62.2	1.8	1.8	58
1N5376B, G	1N5376B	82.65	87	91.35	15	75	760	1	0.5	66	1.7	2.0	54.5
1N5377B, G	1N5377B	86.45	91	95.55	15	75	760	1	0.5	69.2	1.6	2.2	52.5
1N5378B, G	1N5378B	95	100	105	12	90	800	1	0.5	76	1.5	2.5	47.5
1N5379B, G	1N5379B	104.5	110	115.5	12	125	1000	1	0.5	83.6	1.4	2.5	43
1N5380B, G	1N5380B	114	120	126	10	170	1150	1	0.5	91.2	1.3	2.5	39.5
1N5381B, G	1N5381B	123.5	130	136.5	10	190	1250	1	0.5	98.8	1.2	2.5	36.6
1N5382B, G	1N5382B	133	140	147	8	230	1500	1	0.5	106	1.2	2.5	34
1N5383B, G	1N5383B	142.5	150	157.5	8	330	1500	1	0.5	114	1.1	3.0	31.6
1N5384B, G	1N5384B	152	160	168	8	350	1650	1	0.5	122	1.1	3.0	29.4
1N5385B, G	1N5385B	161.5	170	178.5	8	380	1750	1	0.5	129	1.0	3.0	28
1N5386B, G	1N5386B	171	180	189	5	430	1750	1	0.5	137	1.0	4.0	26.4
1N5387B, G	1N5387B	180.5	190	199.5	5	450	1850	1	0.5	144	0.9	5.0	25
1N5388B, G	1N5388B	190	200	210	5	480	1850	1	0.5	152	0.9	5.0	23.6

#### ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted, V<sub>F</sub> = 1.2 V Max @ I<sub>F</sub> = 1.0 A for all types)

Devices listed in *bold, italic* are ON Semiconductor **Preferred** devices. **Preferred** devices are recommended choices for future use and best overall value. 6. **TOLERANCE AND TYPE NUMBER DESIGNATION** 

The JEDEC type numbers shown indicate a tolerance of  $\pm 5\%$ .

7. ZENER VOLTAGE (Vz) and IMPEDANCE ( $I_{ZT}$  and  $I_{ZK}$ )

Test conditions for zener voltage and impedance are as follows:  $I_Z$  is applied 40 ±10 ms prior to reading. Mounting contacts are located 3/8" to 1/2" from the inside edge of mounting clips to the body of the diode ( $T_A = 25^{\circ}C + 8^{\circ}C$ , -2°C).

8. SURGE CURRENT (IR)

Surge current is specified as the maximum allowable peak, non-recurrent square-wave current with a pulse width, PW, of 8.3 ms. The data given in Figure 5 may be used to find the maximum surge current for a square wave of any pulse width between 1 ms and 1000 ms by plotting the applicable points on logarithmic paper. Examples of this, using the 3.3 V and 200 V zener are shown in Figure 6. Mounting contact located as specified in Note 7 ( $T_A = 25^{\circ}C + 8^{\circ}C$ ,  $-2^{\circ}C$ ).

9. VOLTAGE REGULATION (ΔVZ)

The conditions for voltage regulation are as follows: V<sub>Z</sub> measurements are made at 10% and then at 50% of the I<sub>Z</sub> max value listed in the electrical characteristics table. The test current time duration for each V<sub>Z</sub> measurement is 40 ±10 ms. Mounting contact located as specified in Note 7 ( $T_A = 25^{\circ}C + 8^{\circ}C$ , -2°C).

#### 10. MAXIMUM REGULATOR CURRENT (IZM)

The maximum current shown is based on the maximum voltage of a 5% type unit, therefore, it applies only to the B-suffix device. The actual  $I_{ZM}$  for any device may not exceed the value of 5 watts divided by the actual  $V_Z$  of the device.  $T_L = 75^{\circ}C$  at 3/8" maximum from the device body.

†The "G" suffix indicates Pb-Free package available.

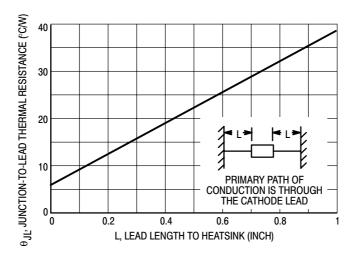
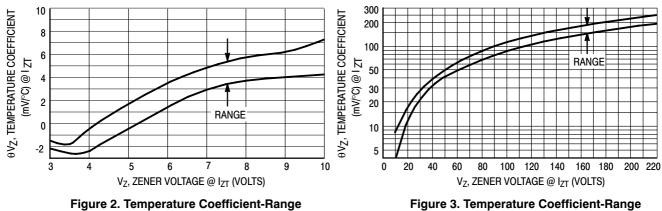


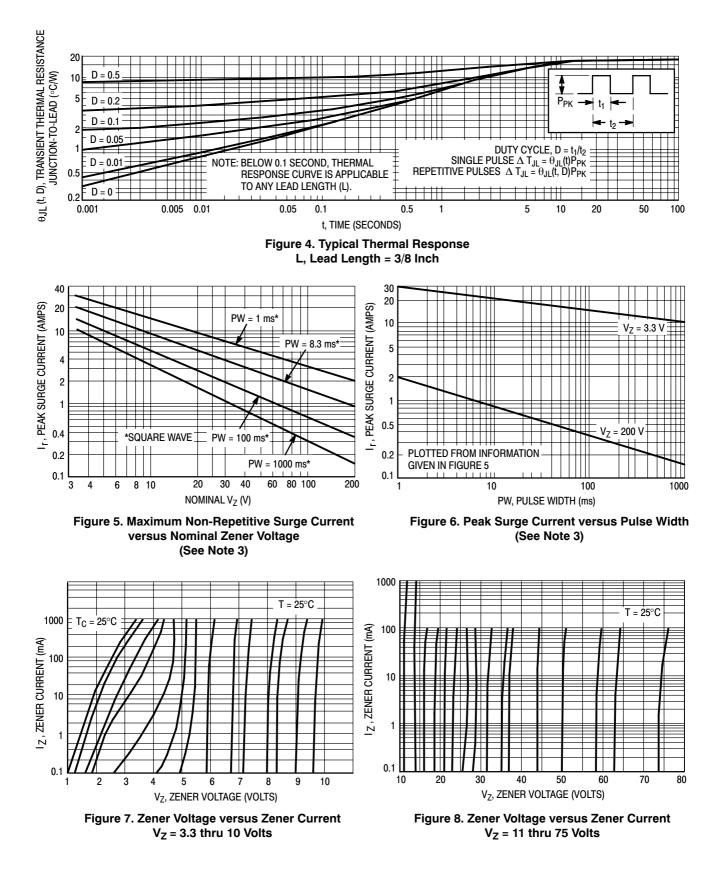
Figure 1. Typical Thermal Resistance

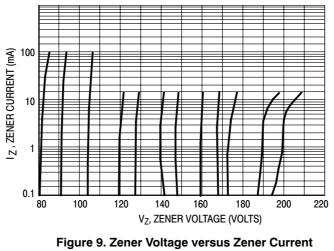
#### **TEMPERATURE COEFFICIENTS**



for Units 3 to 10 Volts

Figure 3. Temperature Coefficient-Range for Units 10 to 220 Volts





V<sub>Z</sub> = 82 thru 200 Volts

#### **APPLICATION NOTE**

Since the actual voltage available from a given Zener diode is temperature dependent, it is necessary to determine junction temperature under any set of operating conditions in order to calculate its value. The following procedure is recommended:

Lead Temperature, T<sub>L</sub>, should be determined from:

$$T_{L} = \theta_{LA} P_{D} + T_{A}$$

 $\theta_{LA}$  is the lead-to-ambient thermal resistance and  $P_D$  is the power dissipation.

Junction Temperature, T<sub>J</sub>, may be found from:

$$\mathsf{T}_{\mathsf{J}} = \mathsf{T}_{\mathsf{L}} + \Delta \mathsf{T}_{\mathsf{J}\mathsf{L}}$$

 $\Delta T_{JL}$  is the increase in junction temperature above the lead temperature and may be found from Figure 4 for a train of power pulses or from Figure 1 for dc power.

$$\Delta T_{JL} = \theta_{JL} P_D$$

For worst-case design, using expected limits of  $I_Z$ , limits of  $P_D$  and the extremes of  $T_J$  ( $\Delta T_J$ ) may be estimated. Changes in voltage,  $V_Z$ , can then be found from:

$$\Delta V = \theta_{VZ} \Delta T_J$$

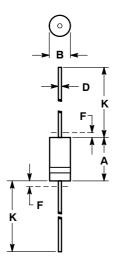
 $\theta_{VZ}$ , the Zener voltage temperature coefficient, is found from Figures 2 and 3.

Under high power-pulse operation, the Zener voltage will vary with time and may also be affected significantly by the zener resistance. For best regulation, keep current excursions as low as possible.

Data of Figure 4 should not be used to compute surge capability. Surge limitations are given in Figure 5. They are lower than would be expected by considering only junction temperature, as current crowding effects cause temperatures to be extremely high in small spots resulting in device degradation should the limits of Figure 5 be exceeded.

#### PACKAGE DIMENSIONS

SURMETIC 40, AXIAL LEAD CASE 017AA-01 ISSUE O



NOTES:

1. CONTROLLING DIMENSION: INCH 2. LEAD DIAMETER AND FINISH NOT CONTROLLED WITHIN DIMENSION F. 3. CATHODE BAND INDICATES POLARITY

	INC	HES	MILLIMETERS				
DIM	MIN	MAX	MIN	MAX			
Α	0.330	0.350	8.38	8.89			
В	0.130	0.145	3.30	3.68			
D	0.037	0.043	0.94	1.09			
F		0.050		1.27			
K	1.000	1.250	25.40	31.75			

SURMETIC is a trademark of Semiconductor Components Industries, LLC (SCILLC).

ON Semiconductor and 💷 are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC observed any end to the provide and the part in the validated for each customer application by customer's technical experts. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications are specified for each customer applications and customer specifications are specified for surgical implant into the body, or other applications are specified for each customer applications are specified for surgical implant into the body, or other applications are accustomer applications and actual performance may any liability of the specified for each customer applications are specified for each customer's technical experts. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications are performed and accustomer applications are performed and accustomer applications are accustomer bit intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

#### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5773-3850

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative